# 1SMA10CAT3G Series, SZ1SMA10CAT3G Series

# 400 Watt Peak Power Zener Transient Voltage Suppressors

## **Bidirectional**

The SMA series is designed to protect voltage sensitive components from high voltage, high energy transients. They have excellent clamping capability, high surge capability, low zener impedance and fast response time. The SMA series is supplied in ON Semiconductor's exclusive, cost-effective, highly reliable SURMETIC<sup>®</sup> package and is ideally suited for use in communication systems, automotive, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications.

#### Features

- Working Peak Reverse Voltage Range 10 V to 78 V
- Standard Zener Breakdown Voltage Range 11.7 V to 91.3 V
- Peak Power 400 Watts @ 1 ms
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- Response Time is Typically < 1 ns
- Flat Handling Surface for Accurate Placement
- Package Design for Top Slide or Bottom Circuit Board Mounting
- Low Profile Package
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These are Pb–Free Devices\*

#### **Mechanical Characteristics:**

**CASE:** Void-free, transfer-molded plastic

**FINISH:** All external surfaces are corrosion resistant and leads are readily solderable

**MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:** 260°C for 10 Seconds

**POLARITY:** Cathode polarity notch does not indicate polarity **MOUNTING POSITION:** Any



## **ON Semiconductor®**

www.onsemi.com

PLASTIC SURFACE MOUNT ZENER OVERVOLTAGE TRANSIENT SUPPRESSORS 10–78 V V<sub>R</sub> 400 W PEAK POWER



SMA CASE 403D PLASTIC



#### MARKING DIAGRAM



xxC = Device Code (Refer to page 3)

- A = Assembly Location
- Y = Year
- WW = Work Week
- = Pb–Free Package

#### **ORDERING INFORMATION**

Device**	Package	Shipping <sup>†</sup>
1SMAxxCAT3G	SMA (Pb-Free)	5,000 / Tape & Reel
SZ1SMAxxCAT3G	SMA (Pb–Free)	5,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*\*The "T3" suffix refers to a 13 inch reel.

#### **DEVICE MARKING INFORMATION** See specific marking information in the device marking

column of the Electrical Characteristics table on page 3 of

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Semiconductor Components Industries, LLC, 2016 April, 2016 – Rev. 13

1

this data sheet.

## 1SMA10CAT3G Series, SZ1SMA10CAT3G Series

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1) @ $T_L = 25^{\circ}C$ , Pulse Width = 1 ms	P <sub>PK</sub>	400	W
DC Power Dissipation @ T <sub>L</sub> = 75°C Measured Zero Lead Length (Note 2) Derate Above 75°C Thermal Resistance from Junction–to–Lead	P <sub>D</sub> R <sub>θJL</sub>	1.5 20 50	W mW/°C °C/W
DC Power Dissipation (Note 3) @ T <sub>A</sub> = 25°C Derate Above 25°C Thermal Resistance from Junction–to–Ambient	P <sub>D</sub> R <sub>θJA</sub>	0.5 4.0 250	W mW/°C °C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

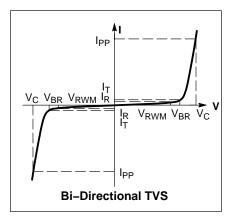
1. 10 X 1000  $\mu$ s, non-repetitive. 2. 1 in square copper pad, FR-4 board.

3. FR-4 board, using ON Semiconductor minimum recommended footprint, as shown in 403B case outline dimensions spec.

### **ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Symbol	Parameter					
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current					
V <sub>C</sub>	Clamping Voltage @ IPP					
V <sub>RWM</sub>	Working Peak Reverse Voltage					
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>					
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>					
Ι <sub>Τ</sub>	Test Current					



#### **ELECTRICAL CHARACTERISTICS**

		V <sub>RWM</sub>		Breakdown Voltage			Vc @ I <sub>PP</sub> (Note 6)		С Тур.	
	Device		I <sub>R</sub> @ V <sub>RWM</sub>	V <sub>RWM</sub> V <sub>BR</sub> (Volts) (Note 5)			@ I <sub>T</sub>	٧c	IPP	(Note 7)
Device*	Marking	Volts	μΑ	Min	Nom	Max	mA	Volts	Amps	pF
1SMA10CAT3G	QXC	10	2.5	11.1	11.69	12.27	1.0	17.0	23.5	580
1SMA12CAT3G	REC	12	2.5	13.3	14.00	14.70	1.0	19.9	20.1	490
1SMA13CAT3G	RGC	13	2.5	14.4	15.16	15.92	1.0	21.5	18.6	455
1SMA15CAT3G	RMC	15	2.5	16.7	17.58	18.46	1.0	24.4	16.4	400
1SMA16CAT3G	RPC	16	2.5	17.8	18.74	19.67	1.0	26.0	15.4	375
1SMA18CAT3G	RTC	18	2.5	20	21.06	22.11	1.0	29.2	13.7	335
1SMA20CAT3G	RVC	20	2.5	22.2	23.37	24.54	1.0	32.4	12.3	305
1SMA24CAT3G	RZC	24	2.5	26.7	28.11	29.51	1.0	38.9	10.3	260
1SMA26CAT3G	SEC	26	2.5	28.9	30.42	31.94	1.0	42.1	9.5	240
1SMA28CAT3G	SGC	28	2.5	31.1	32.74	34.37	1.0	45.4	8.8	225
1SMA30CAT3G	SKC	30	1.0	33.3	35.06	36.81	1.0	48.4	8.3	210
1SMA33CAT3G	SMC	33	2.5	36.7	38.63	40.56	1.0	53.3	7.5	190
1SMA36CAT3G	SPC	36	2.5	40	42.11	44.21	1.0	58.1	6.9	175
1SMA40CAT3G	SRC	40	2.5	44.4	46.74	49.07	1.0	64.5	6.2	160
1SMA48CAT3G	SXC	48	2.5	53.3	56.11	58.91	1.0	77.4	5.2	135
1SMA58CAT3G	TGC	58	2.5	64.4	67.79	71.18	1.0	93.6	4.3	115
1SMA60CAT3G	TKC	60	2.5	66.7	70.21	73.72	1.0	96.8	4.1	110
1SMA70CAT3G	TPC	70	2.5	77.8	81.90	85.99	1.0	113	3.5	95
1SMA78CAT3G	TTC	78	2.5	86.7	91.27	95.83	1.0	126	3.2	90

4. A transient suppressor is normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal to or greater than the DC or continuous peak operating voltage level

5.  $V_{BR}$  measured at pulse test current  $I_T$  at an ambient temperature of 25°C 6. Surge current waveform per Figure 2 and derate per Figure 3

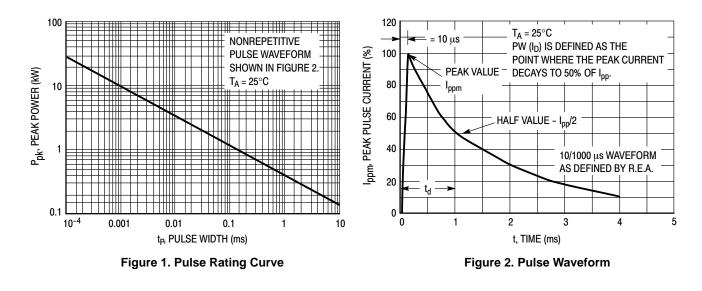
7. Bias voltage = 0 V, F = 1.0 MHz,  $T_J = 25^{\circ}C$ .

†Please see 1SMA5.0AT3 to 1SMA78AT3 for Unidirectional devices.

\* Include SZ-prefix devices where applicable.

## 1SMA10CAT3G Series, SZ1SMA10CAT3G Series

### RATING AND TYPICAL CHARACTERISTIC CURVES



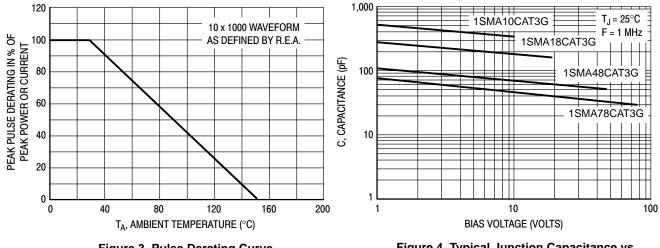


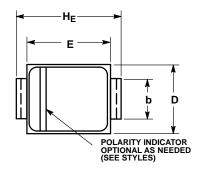
Figure 3. Pulse Derating Curve

Figure 4. Typical Junction Capacitance vs. Bias Voltage

### 1SMA10CAT3G Series, SZ1SMA10CAT3G Series

#### PACKAGE DIMENSIONS

SMA CASE 403D ISSUE H

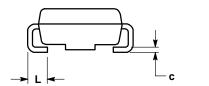


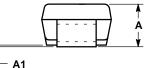
NOTES 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982

2

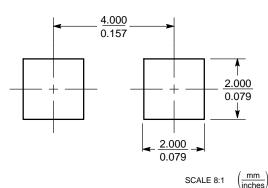
2. CONTROLLING DIMENSION: INCH. 3. DIMENSION b SHALL BE MEASURED WITHIN DIMENSION L.

	м	ILLIMETE	RS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.97	2.10	2.20	0.078	0.083	0.087	
A1	0.05	0.10	0.20	0.002	0.004	0.008	
b	1.27	1.45	1.63	0.050	0.057	0.064	
С	0.15	0.28	0.41	0.006	0.011	0.016	
D	2.29	2.60	2.92	0.090	0.103	0.115	
E	4.06	4.32	4.57	0.160	0.170	0.180	
HE	4.83	5.21	5.59	0.190	0.205	0.220	
L	0.76	1.14	1.52	0.030	0.045	0.060	





SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SURMETIC is a registered trademark of Semiconductor Components Industries, LLC.

💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice ON Semiconductor and to any products herein. SCILC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative